

# CSD18542KCS 60 V N-Channel NexFET™ Power MOSFET

## 1 Features

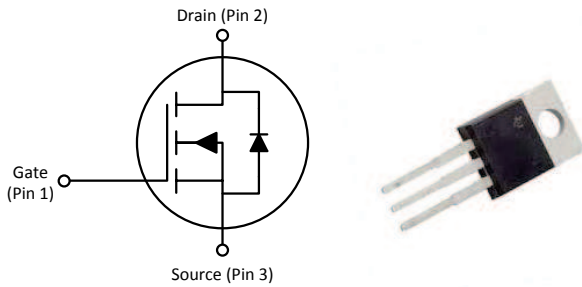
- Ultra-Low  $Q_g$  and  $Q_{gd}$
- Low Thermal Resistance
- Avalanche Rated
- Logic Level
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- TO-220 Plastic Package

## 2 Applications

- DC-DC Conversion
- Secondary Side Synchronous Rectifier
- Motor Control

## 3 Description

This 60 V, 3.3 mΩ, TO-220 NexFET™ power MOSFET is designed to minimize losses in power conversion applications.



### Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
$V_{DS}$	Drain-to-source voltage	60		V
$Q_g$	Gate charge total (10 V)	44		nC
$Q_{gd}$	Gate charge gate-to-drain	6.9		nC
$R_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}$	4.0	mΩ
		$V_{GS} = 10\text{ V}$	3.3	mΩ
$V_{GS(th)}$	Threshold voltage	1.8		V

### Ordering Information<sup>(1)</sup>

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD18542KCS	50	Tube	TO-220 Plastic Package	Tube

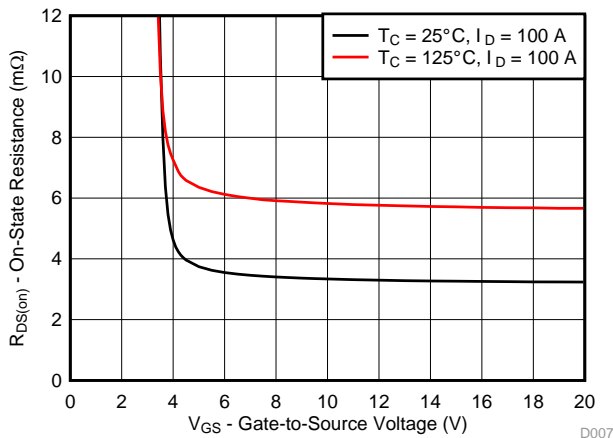
(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Absolute Maximum Ratings

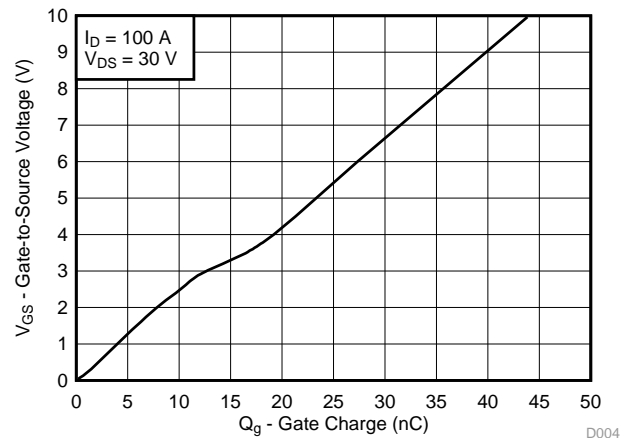
$T_A = 25^\circ\text{C}$		VALUE	UNIT
$V_{DS}$	Drain-to-source voltage	60	V
$V_{GS}$	Gate-to-source voltage	$\pm 20$	V
$I_D$	Continuous drain current (package limited)	200	A
	Continuous drain current (silicon limited), $T_C = 25^\circ\text{C}$	170	
	Continuous drain current (silicon limited), $T_C = 100^\circ\text{C}$	120	
$I_{DM}$	Pulsed drain current <sup>(1)</sup>	400	A
$P_D$	Power dissipation	200	W
$T_J, T_{stg}$	Operating junction, Storage temperature	-55 to 175	$^\circ\text{C}$
$E_{AS}$	Avalanche energy, single pulse $I_D = 75\text{ A}, L = 0.1\text{ mH}, R_G = 25\ \Omega$	281	mJ

(1) Max  $R_{\theta JC} = 0.6^\circ\text{C}/\text{W}$ , pulse duration  $\leq 100\ \mu\text{s}$ , duty cycle  $\leq 1\%$

**$R_{DS(on)}$  vs  $V_{GS}$**



**Gate Charge**



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## 4 Revision History

DATE	REVISION	NOTES
June 2015	*	Initial release.

## 5 Specifications

### 5.1 Electrical Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>STATIC CHARACTERISTICS</b>						
$V_{DSS}$	Drain-to-source voltage	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	60			V
$I_{DSS}$	Drain-to-source leakage current	$V_{GS} = 0\text{ V}, V_{DS} = 48\text{ V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate-to-source leakage current	$V_{DS} = 0\text{ V}, V_{GS} = 20\text{ V}$			100	nA
$V_{GS(th)}$	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	1.5	1.8	2.2	V
$R_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}, I_D = 100\text{ A}$		4.0	5.1	m $\Omega$
		$V_{GS} = 10\text{ V}, I_D = 100\text{ A}$		3.3	4.0	m $\Omega$
$g_{fs}$	Transconductance	$V_{DS} = 30\text{ V}, I_D = 100\text{ A}$		198		S
<b>DYNAMIC CHARACTERISTICS</b>						
$C_{iss}$	Input capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 30\text{ V}, f = 1\text{ MHz}$		3900	5070	pF
$C_{oss}$	Output capacitance			570	740	pF
$C_{rss}$	Reverse transfer capacitance			11	14	pF
$R_G$	Series gate resistance			1.3	2.6	$\Omega$
$Q_g$	Gate charge total (4.5 V)	$V_{DS} = 30\text{ V}, I_D = 100\text{ A}$		21	27	nC
$Q_g$	Gate charge total (10 V)			44	57	nC
$Q_{gd}$	Gate charge gate-to-drain			6.9		nC
$Q_{gs}$	Gate charge gate-to-source			10		nC
$Q_{g(th)}$	Gate charge at $V_{th}$			7.3		nC
$Q_{oss}$	Output charge		$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$		63	
$t_{d(on)}$	Turn on delay time	$V_{DS} = 30\text{ V}, V_{GS} = 10\text{ V}, I_{DS} = 100\text{ A}, R_G = 0\ \Omega$		6		ns
$t_r$	Rise time			5		ns
$t_{d(off)}$	Turn off delay time			18		ns
$t_f$	Fall time			21		ns
<b>DIODE CHARACTERISTICS</b>						
$V_{SD}$	Diode forward voltage	$I_{SD} = 100\text{ A}, V_{GS} = 0\text{ V}$		0.9	1.0	V
$Q_{rr}$	Reverse recovery charge	$V_{DS} = 30\text{ V}, I_F = 100\text{ A}, di/dt = 300\text{ A}/\mu\text{s}$		148		nC
$t_{rr}$	Reverse recovery time			53		ns

### 5.2 Thermal Information

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance			0.6	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Junction-to-ambient thermal resistance			62	$^\circ\text{C}/\text{W}$

### 5.3 Typical MOSFET Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

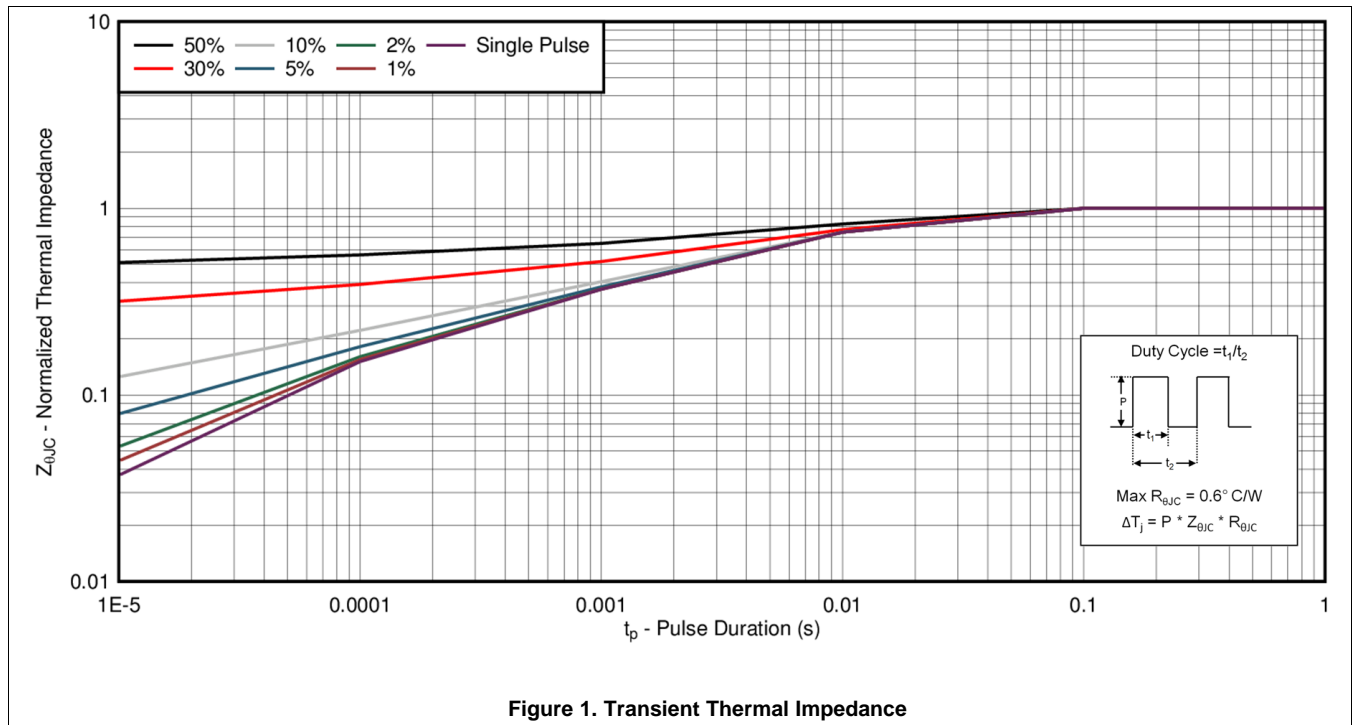


Figure 1. Transient Thermal Impedance

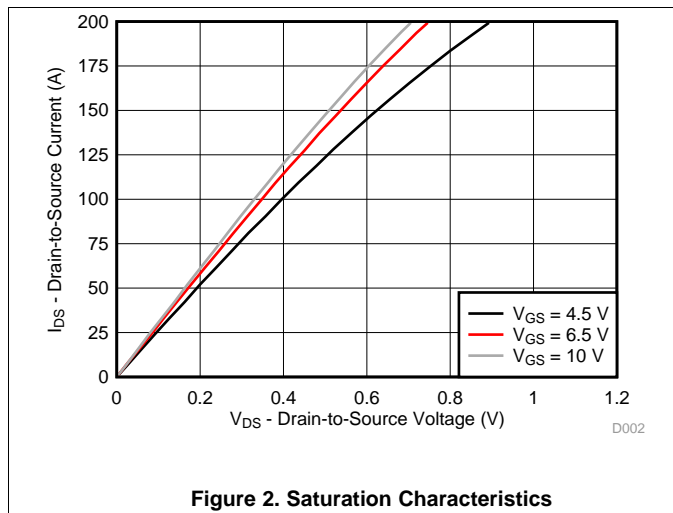


Figure 2. Saturation Characteristics

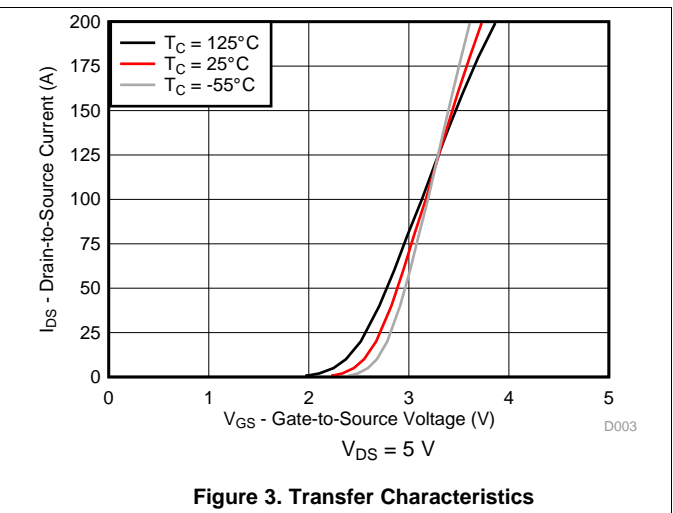


Figure 3. Transfer Characteristics

Typical MOSFET Characteristics (continued)

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

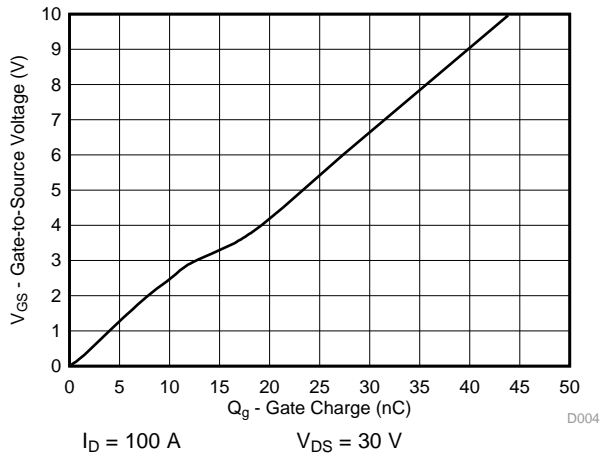


Figure 4. Gate Charge

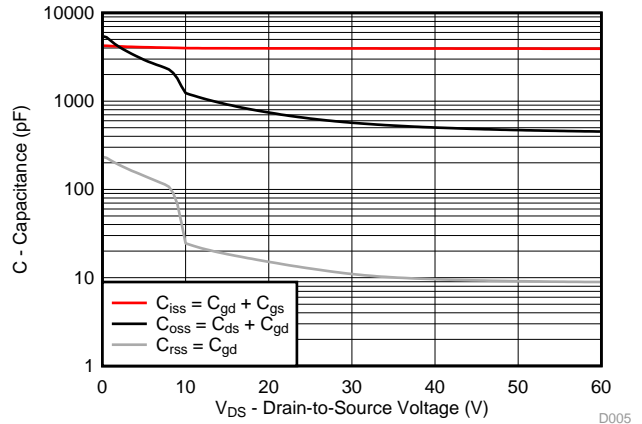


Figure 5. Capacitance

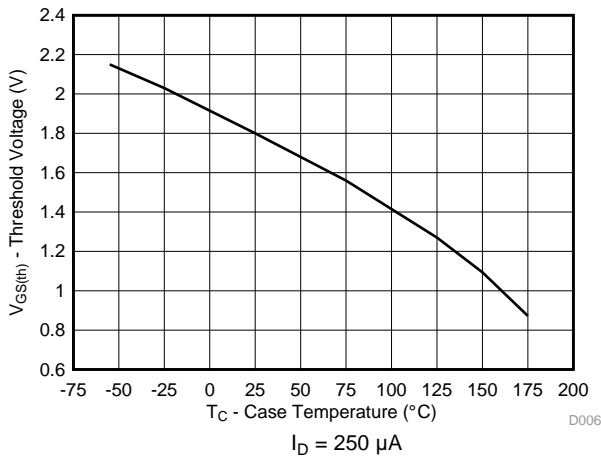


Figure 6. Threshold Voltage vs Temperature

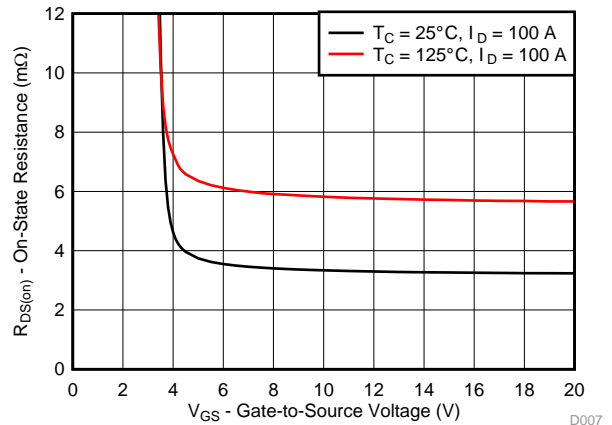


Figure 7. On-State Resistance vs Gate-to-Source Voltage

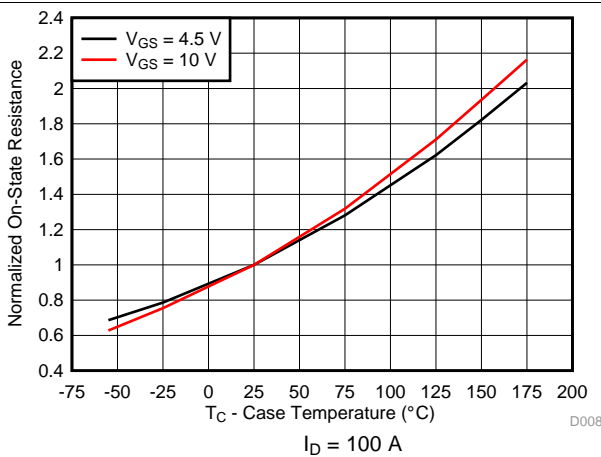


Figure 8. Normalized On-State Resistance vs Temperature

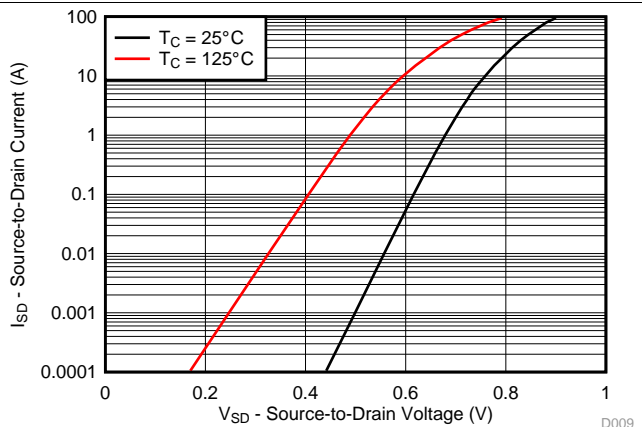


Figure 9. Typical Diode Forward Voltage

### Typical MOSFET Characteristics (continued)

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

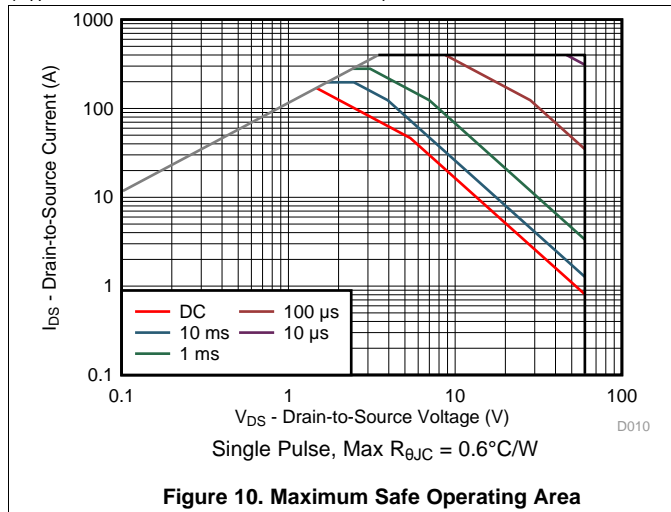


Figure 10. Maximum Safe Operating Area

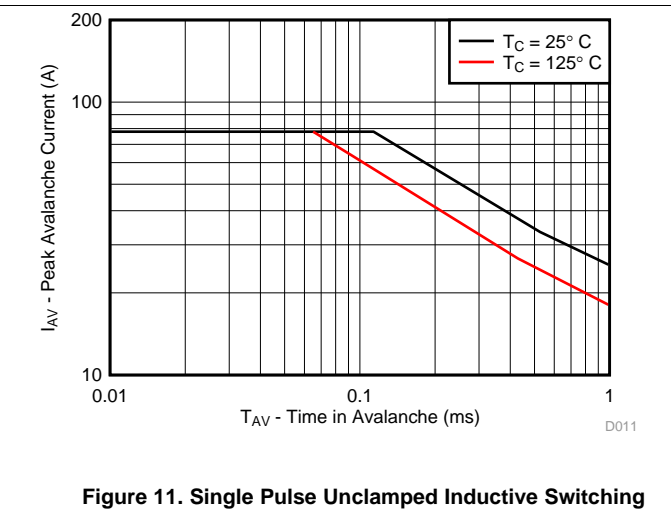


Figure 11. Single Pulse Unclamped Inductive Switching

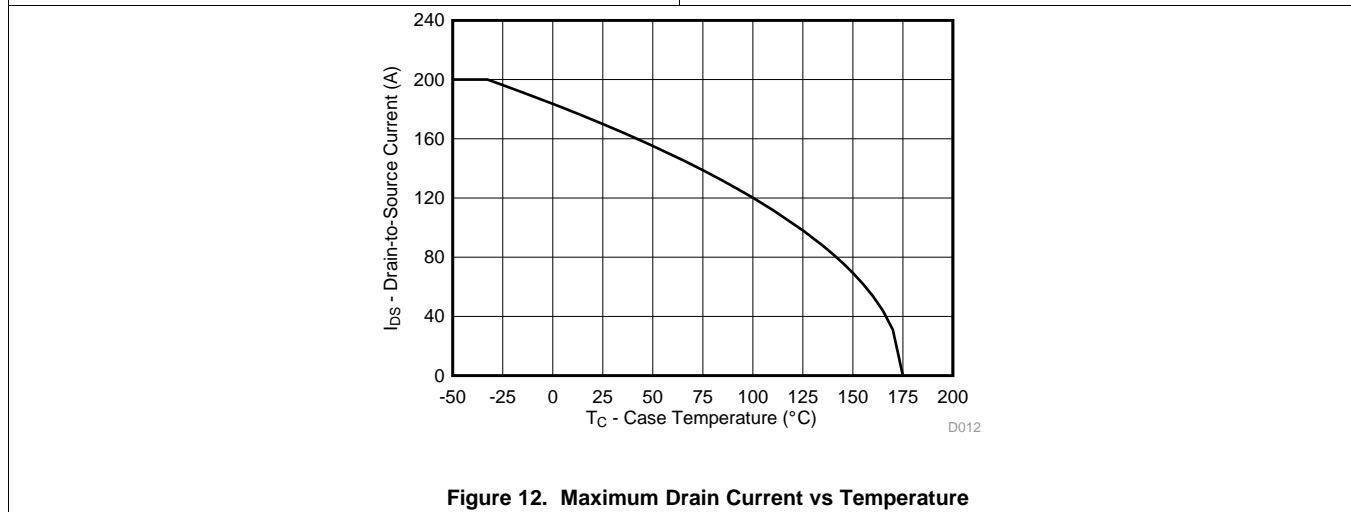


Figure 12. Maximum Drain Current vs Temperature

## 6 Device and Documentation Support

### 6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 6.2 Trademarks

NexFET, E2E are trademarks of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.4 Glossary

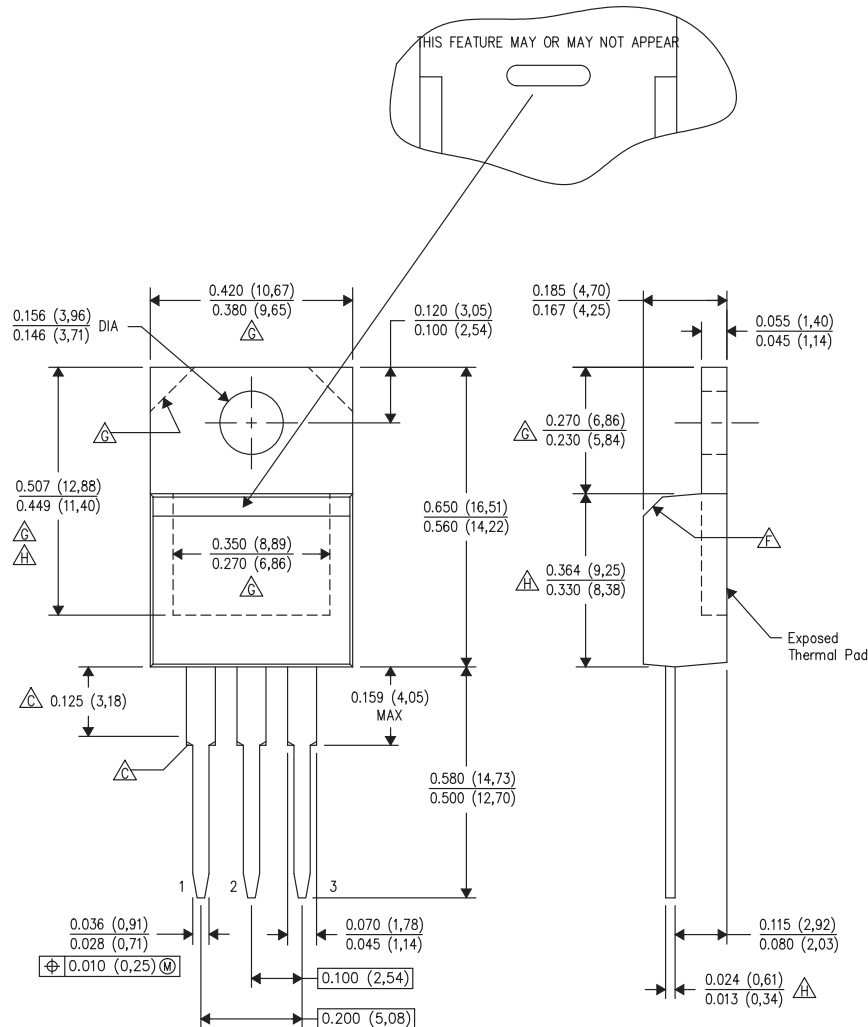
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

### 7.1 KCS Package Dimensions



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle$  Lead dimensions are not controlled within this area. Chamfer may or may not appear
  - D. All lead dimensions apply before solder dip.
  - E. The center lead is in electrical contact with the mounting tab.
  - $\triangle$  The chamfer is optional.
  - $\triangle$  Thermal pad contour optional within these dimensions.
  - $\triangle$  Falls within JEDEC TO-220 variation AB, except minimum lead thickness, minimum exposed pad length, and maximum body length.

#### Pin Configuration

POSITION	DESIGNATION
Pin 1	Gate
Pin 2 / Tab	Drain
Pin 3	Source



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD18542KCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS Exempt)	CU SN	N / A for Pkg Type	-55 to 175	CSD18542KCS	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

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TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

### Products

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### Applications

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Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
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